

| Parameter              | Rating | Units                                |
|------------------------|--------|--------------------------------------|
| Blocking Voltage       | 350    | V <sub>P</sub>                       |
| Load Current           | 120    | mA <sub>rms</sub> / mA <sub>DC</sub> |
| On-Resistance (max)    | 30     | Ω                                    |
| LED Current to operate | 2      | mA                                   |

### Features

- 1500V<sub>rms</sub> Input/Output Isolation
- No EMI/RFI Generation
- Immune to Radiated EM Fields
- Tape & Reel Version Available
- Small 8-Pin SOIC Package
- Flammability Rating UL 94 V-0

### Applications

- Telecommunications
- Security
  - Passive Infrared Detectors (PIR)
  - Data Signaling
  - Sensor Circuitry
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Medical Equipment—Patient/Equipment Isolation
- Industrial Controls

### Description

The CPC2030N is a miniature device with two independent normally-open (1-Form-A) solid state relays in an 8-pin SOIC package that employs optically coupled MOSFET technology to provide 1500V<sub>rms</sub> of input to output isolation.

Optically coupled outputs using the patented OptoMOS architecture are controlled by a highly efficient infrared LED.

The CPC2030N uses IXYS Integrated Circuits' state of the art, double-molded vertical construction packaging to produce one of the world's smallest relays. The CPC2030N offers substantial board space savings over the competitor's larger 8-pin SOIC relay.

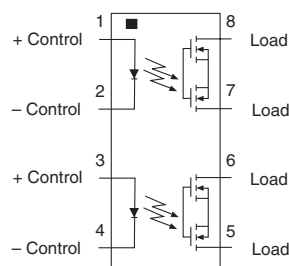
### Approvals

- UL Recognized Component: File E76270
- TUV EN 62368-1: Certificate # B 082667 0008

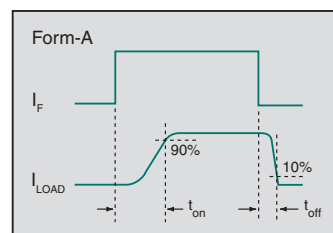
### Ordering Information

| Part #     | Description            |
|------------|------------------------|
| CPC2030N   | 8-Pin SOIC (50/tube)   |
| CPC2030NTR | 8-Pin SOIC (2000/reel) |

### Pin Configuration



### Switching Characteristics of Normally-Open (Form A) Devices



## Absolute Maximum Ratings @ 25°C

| Parameter                            | Ratings     | Units            |
|--------------------------------------|-------------|------------------|
| Blocking Voltage                     | 350         | V <sub>P</sub>   |
| Reverse Input Voltage                | 5           | V                |
| Input Control Current<br>Peak (10ms) | 50          | mA               |
|                                      | 1           | A                |
| Input Power Dissipation              | 70          | mW               |
| Total Power Dissipation <sup>1</sup> | 600         | mW               |
| Isolation Voltage, Input to Output   | 1500        | V <sub>rms</sub> |
| Operational Temperature, Ambient     | -40 to +85  | °C               |
| Storage Temperature                  | -40 to +125 | °C               |

<sup>1</sup> Derate linearly 5mW / °C

*Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.*

*Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.*

## Electrical Characteristics @ 25°C

| Parameter                                       | Conditions                                       | Symbol            | Min | Typ  | Max  | Units                                |
|-------------------------------------------------|--------------------------------------------------|-------------------|-----|------|------|--------------------------------------|
| <b>Output Characteristics</b>                   |                                                  |                   |     |      |      |                                      |
| Blocking Voltage                                | I <sub>L</sub> =1μA                              | V <sub>DRM</sub>  | 350 | -    | -    | V                                    |
| Load Current<br>Continuous <sup>1</sup><br>Peak | I <sub>F</sub> =2mA                              | I <sub>L</sub>    | -   | -    | 120  | mA <sub>rms</sub> / mA <sub>DC</sub> |
|                                                 | t=10ms                                           | I <sub>LPK</sub>  | -   | -    | ±350 | mA <sub>p</sub>                      |
| On-Resistance <sup>2</sup>                      | I <sub>L</sub> =120mA                            | R <sub>ON</sub>   | -   | 19.5 | 30   | Ω                                    |
| Off-State Leakage Current                       | V <sub>L</sub> =350V <sub>P</sub>                | I <sub>LEAK</sub> | -   | -    | 1    | μA                                   |
| <b>Switching Speeds</b>                         |                                                  |                   |     |      |      |                                      |
| Turn-On                                         | I <sub>F</sub> =5mA, V <sub>L</sub> =10V         | t <sub>on</sub>   | -   | 0.76 | 2    | ms                                   |
| Turn-Off                                        |                                                  | t <sub>off</sub>  | -   | 0.36 | 1    |                                      |
| Output Capacitance                              | I <sub>F</sub> =0mA, V <sub>L</sub> =50V, f=1MHz | C <sub>OUT</sub>  | -   | 9    | -    | pF                                   |
| Capacitance, Input to Output                    | V <sub>IO</sub> =0V, f=1MHz                      | C <sub>IO</sub>   | -   | 1    | -    | pF                                   |
| <b>Input Characteristics</b>                    |                                                  |                   |     |      |      |                                      |
| Input Control Current to Activate <sup>3</sup>  | I <sub>L</sub> =120mA                            | I <sub>F</sub>    | -   | -    | 2    | mA                                   |
| Input Control Current to Deactivate             | -                                                | I <sub>F</sub>    | 0.1 | -    | -    | mA                                   |
| Input Voltage Drop                              | I <sub>F</sub> =5mA                              | V <sub>F</sub>    | 0.9 | 1.36 | 1.5  | V                                    |
| Reverse Input Current                           | V <sub>R</sub> =5V                               | I <sub>R</sub>    | -   | -    | 10   | μA                                   |

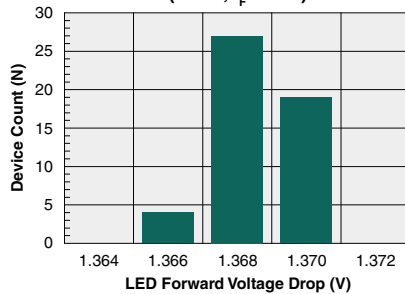
<sup>1</sup> Load current derates linearly from 120mA @ 25°C to 60mA @ 85°C, and must be derated for both poles operating simultaneously.

<sup>2</sup> Measurement taken within 1 second of on-time.

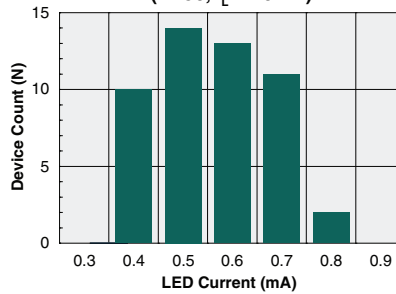
<sup>3</sup> For applications requiring high temperature operation (greater than 60°C) a minimum LED drive current of 4mA is recommended.

# PERFORMANCE DATA\*

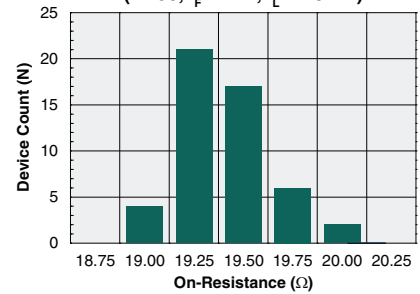
Typical LED Forward Voltage Drop  
(N=50,  $I_F=5\text{mA}$ )



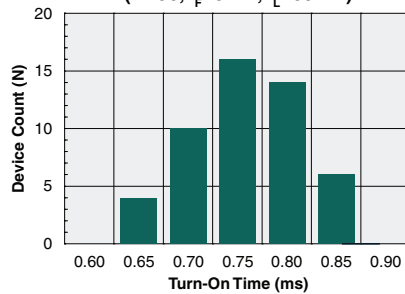
Typical  $I_F$  for Switch Operation  
(N=50,  $I_L=120\text{mA}$ )



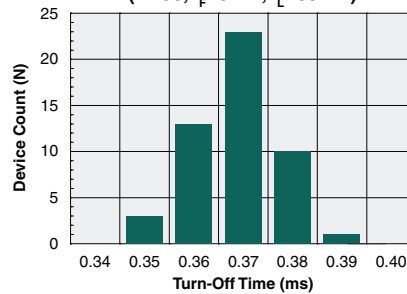
Typical On-Resistance Distribution  
(N=50,  $I_F=2\text{mA}$ ,  $I_L=120\text{mA}$ )



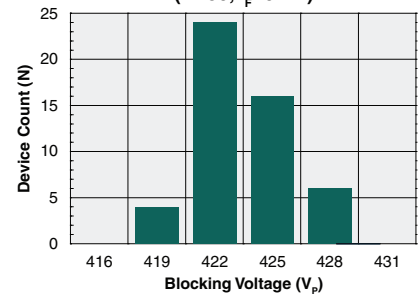
Typical Turn-On Time  
(N=50,  $I_F=5\text{mA}$ ,  $I_L=60\text{mA}$ )



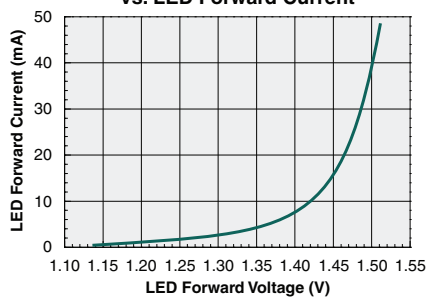
Typical Turn-Off Time  
(N=50,  $I_F=5\text{mA}$ ,  $I_L=60\text{mA}$ )



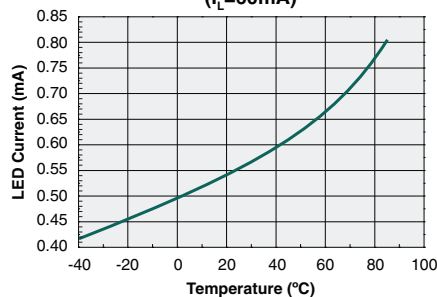
Typical Blocking Voltage Distribution  
(N=50,  $I_F=0\text{mA}$ )



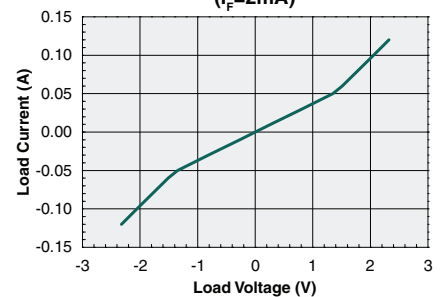
LED Forward Voltage  
vs. LED Forward Current



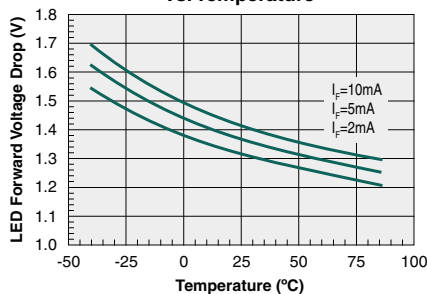
Typical  $I_F$  for Switch Operation  
( $I_L=60\text{mA}$ )



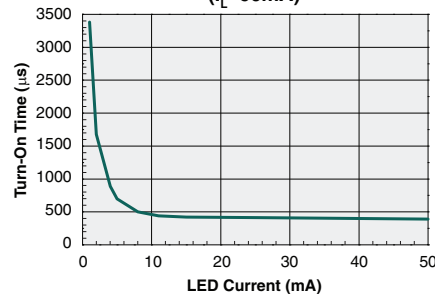
Typical Load Current  
vs. Load Voltage  
( $I_F=2\text{mA}$ )



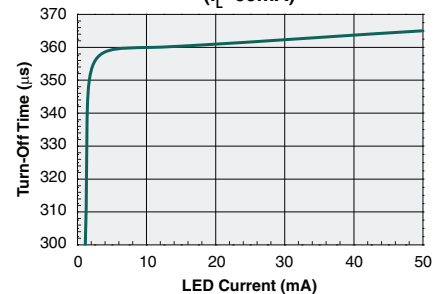
Typical LED Forward Voltage Drop  
vs. Temperature



Typical Turn-On Time  
vs. LED Forward Current  
( $I_L=60\text{mA}$ )

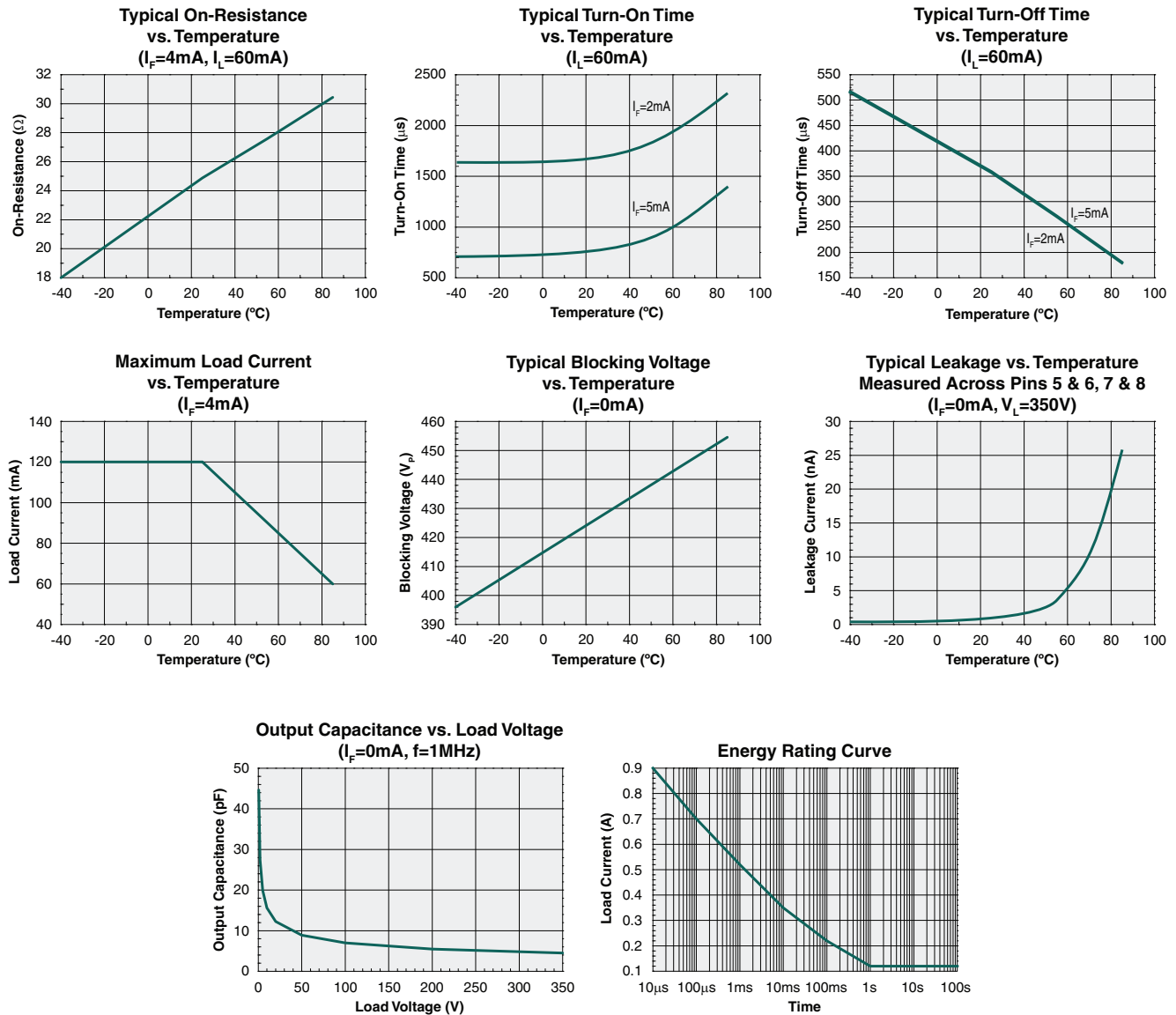


Typical Turn-Off Time  
vs. LED Forward Current  
( $I_L=60\text{mA}$ )



\*Unless otherwise noted, data presented in these graphs is typical of device operation at  $25^{\circ}\text{C}$ .

## PERFORMANCE DATA\*



\*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

## Manufacturing Information

### Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

| Device   | Moisture Sensitivity Level (MSL) Classification |
|----------|-------------------------------------------------|
| CPC2030N | MSL 3                                           |

### ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard **JESD-625**.

### Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature ( $T_C$ ) and the maximum dwell time the body temperature of these surface mount devices may be ( $T_C - 5$ )°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

| Device   | Classification Temperature ( $T_C$ ) | Dwell Time ( $t_p$ ) | Max Reflow Cycles |
|----------|--------------------------------------|----------------------|-------------------|
| CPC2030N | 260°C                                | 30 seconds           | 3                 |

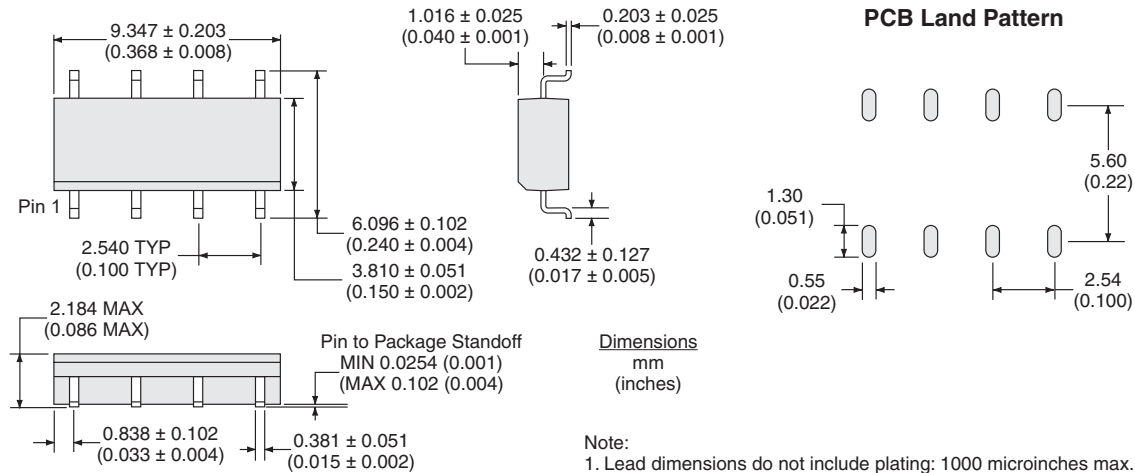
### Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

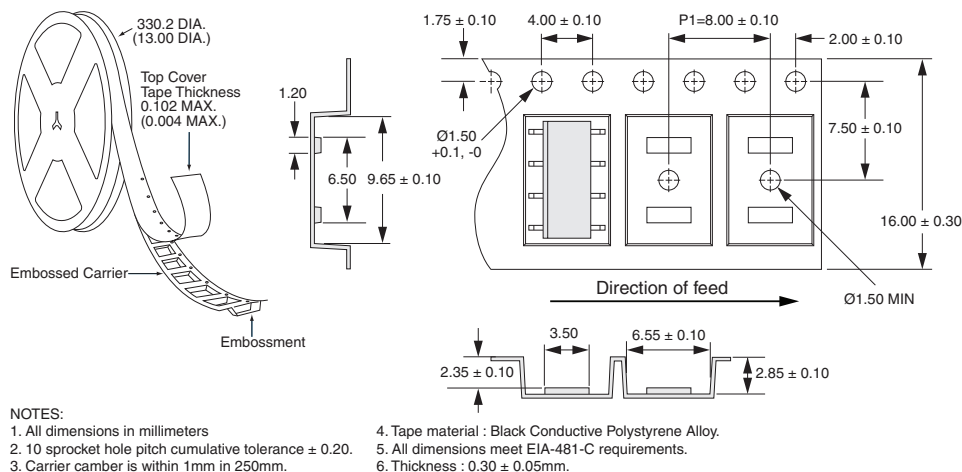


## MECHANICAL DIMENSIONS

### CPC2030N



### CPC2030NTR Tape & Reel



For additional information please visit our website at: <https://www.ixysic.com>